

James Lee

List of Publications by Year in descending order

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11

papers

2,427

citations

840776

11

h-index

1281871

11

g-index

11

all docs

11

docs citations

11

times ranked

4937

citing authors

#	ARTICLE	IF	CITATIONS
1	Direct observation of the transition from indirect to direct bandgap in atomically thin epitaxial MoSe ₂ . <i>Nature Nanotechnology</i> , 2014, 9, 111-115.	31.5	1,129
2	Interfacial mode coupling as the origin of the enhancement of T _c in FeSe films on SrTiO ₃ . <i>Nature</i> , 2014, 515, 245-248.	27.8	567
3	Femtosecond electron-phonon lock-in by photoemission and x-ray free-electron laser. <i>Science</i> , 2017, 357, 71-75.	12.6	177
4	Observation of universal strong orbital-dependent correlation effects in iron chalcogenides. <i>Nature Communications</i> , 2015, 6, 7777.	12.8	148
5	Asymmetry of collective excitations in electron- and hole-doped cuprate superconductors. <i>Nature Physics</i> , 2014, 10, 883-889.	16.7	106
6	Superconducting Gap Anisotropy in Monolayer FeSe Thin Film. <i>Physical Review Letters</i> , 2016, 117, 117001.	7.8	93
7	Distinctive orbital anisotropy observed in the nematic state of a FeSe thin film. <i>Physical Review B</i> , 2016, 94, .	3.2	80
8	Origin of the low critical observing temperature of the quantum anomalous Hall effect in V-doped (Bi, Sb)₂Te₃ film. <i>Scientific Reports</i> , 2016, 6, 32732.	3.3	42
9	Intrinsic ultrathin topological insulators grown via molecular beam epitaxy characterized by <i>in-situ</i> angle resolved photoemission spectroscopy. <i>Applied Physics Letters</i> , 2012, 101, .	3.3	31
10	Charge-orbital-lattice coupling effects in the <math>\langle mml:math> xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:mi>d</mml:mi><mml:mi>d</mml:mi></mml:mrow></math> profile of one-dimensional cuprates. <i>Physical Review B</i> , 2014, 89, .		
11	Interface Ferroelectric Transition near the Gap-Opening Temperature in a Single-Unit-Cell FeSe Film Grown on Nb-Doped SrTiO ₃ Substrate. <i>Physical Review Letters</i> , 2015, 114, 037002.	7.8	23